

# LM8261 Single RRIO, High Output Current & Unlimited Cap Load Op Amp in SOT-23-5

Check for Samples: LM8261

#### **FEATURES**

 $(V_S = 5V, T_A = 25^{\circ}C, Typical Values Unless Specified).$ 

- GBWP 21MHz
- Wide Supply Voltage Range 2.5V to 30V
- Slew Rate 12V/µs
- Supply Current 0.97 mA
- Cap Load Limit Unlimited
- Output Short Circuit Current +53mA/-75mA
- ±5% Settling Time 400ns (500pF, 100mV<sub>PP</sub> step)
- Input common mode voltage 0.3V beyond rails
- Input voltage noise 15nV/√Hz
- Input current noise 1pA/√Hz
- THD+N < 0.05%</li>

#### **APPLICATIONS**

- TFT-LCD flat panel V<sub>COM</sub> driver
- A/D converter buffer
- High side/low side sensing
- Headphone amplifier

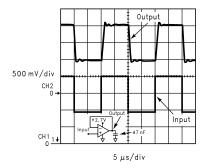


Figure 1. Output Response with Heavy Capacitive Load

#### DESCRIPTION

The LM8261 is a Rail-to-Rail input and output Op Amp which can operate with a wide supply voltage range. This device has high output current drive, greater than Rail-to-Rail input common mode voltage range, unlimited capacitive load drive capability, and provides tested and guaranteed high speed and slew rate while requiring only 0.97mA supply current. It is specifically designed to handle the requirements of flat panel TFT panel V<sub>COM</sub> driver applications as well as being suitable for other low power, and medium speed applications which require ease of use and enhanced performance over existing devices.

Greater than Rail-to-Rail input common mode voltage range with 50dB of Common Mode Rejection, allows high side and low side sensing, among many applications, without having any concerns over exceeding the range and no compromise in accuracy. Exceptionally wide operating supply voltage range of 2.5V to 30V alleviates any concerns over functionality under extreme conditions and offers flexibility of use in multitude of applications. In addition, most device parameters are insensitive to power supply variations; this design enhancement is yet another step in simplifying its usage. The output stage has low distortion (0.05% THD+N) and can supply a respectable amount of current (15mA) with minimal headroom from either rail (300mV).

The LM8261 is offered in the space saving SOT-23-5 package.

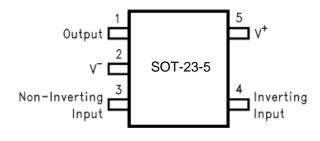


Figure 2. SOT-23-5 Top View



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

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Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



### ABSOLUTE MAXIMUM RATINGS(1)

ECD Television	Human Body Model (2)	2KV
ESD Tolerance	Machine Model (3)	200V
V <sub>IN</sub> Differential		+/-10V
Output Short Circuit Duration		See <sup>(4)(5)</sup>
Supply Voltage (V <sup>+</sup> - V <sup>-</sup> )		32V
Voltage at Input/Output pins		V <sup>+</sup> +0.8V, V <sup>−</sup> −0.1V
Storage Temperature Range		−65°C to +150°C
Junction Temperature (6)		+150°C
Soldering Information:	Infrared or Convection (20 sec.)	235°C
	Wave Soldering (10 sec.)	260°C

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Rating indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see 2.7V Electrical Characteristics.
- (2) Human Body Model is 1.5kΩ in series with 100pF.
- (3) Machine Model, 0Ω is series with 200pF.
- (4) Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C.
- (5) Allowable Output Short Circuit duration is infinite for V<sub>S</sub> ≤ 6V at room temperature and below. For V<sub>S</sub> > 6V, allowable short circuit duration is 1.5ms.
- (6) The maximum power dissipation is a function of  $T_{J(max)}$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any ambient temperature is  $P_D = (T_{J(MAX)} T_A)/\theta_{JA}$ . All numbers apply for packages soldered directly onto a PC board.

#### **OPERATING RATINGS**

Supply Voltage (V <sup>+</sup> - V <sup>-</sup> )		2.5V to 30V
Temperature Range <sup>(1)</sup>		−40°C to +85°C
Package Thermal Resistance, $\theta_{JA}$ , (1)	SOT-23-5	325°C/W

(1) The maximum power dissipation is a function of  $T_{J(max)}$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any ambient temperature is  $P_D = (T_{J(MAX)} - T_A)/\theta_{JA}$ . All numbers apply for packages soldered directly onto a PC board.



#### 2.7V ELECTRICAL CHARACTERISTICS

Unless otherwise specified, all limits guaranteed for  $T_A = 25^{\circ}C$ ,  $V^+ = 2.7V$ ,  $V^- = 0V$ ,  $V_{CM} = 0.5V$ ,  $V_O = V^+/2$ , and  $R_L > 1M\Omega$  to V<sup>-</sup>. **Boldface** limits apply at the temperature extremes. (1)

Symbol	Parameter	Condition	Typ <sup>(2)</sup>	Limit <sup>(3)</sup>	Units
V <sub>OS</sub>	Input Offset Voltage	$V_{CM} = 0.5V \& V_{CM} = 2.2V$	+/-0.7	+/-5 <b>+/-7</b>	mV max
TC V <sub>OS</sub>	Input Offset Average Drift	$V_{CM} = 0.5V \& V_{CM} = 2.2V^{(4)}$	+/-2	_	μV/C
I <sub>B</sub>	Input Bias Current	$V_{CM} = 0.5V^{(5)}$	-1.20	-2.00 <b>-2.70</b>	μA
		$V_{CM} = 2.2V^{(5)}$	+0.49	+1.00 <b>+1.60</b>	max
I <sub>OS</sub>	Input Offset Current	$V_{CM} = 0.5V \& V_{CM} = 2.2V$	20	250 <b>400</b>	nA max
CMRR	Common Mode Rejection Ratio	V <sub>CM</sub> stepped from 0V to 1.0V	100	76 <b>60</b>	
		V <sub>CM</sub> stepped from 1.7V to 2.7V	100		dB min
		V <sub>CM</sub> stepped from 0V to 2.7V	70	58 <b>50</b>	
+PSRR	Positive Power Supply Rejection Ratio	$V^+ = 2.7V$ to 5V	104	78 <b>74</b>	dB min
CMVR	Input Common-Mode Voltage Range	CMRR > 50dB	-0.3	-0.1 <b>0.0</b>	V max
			3.0	2.8 <b>2.7</b>	V min
A <sub>VOL</sub>	Large Signal Voltage Gain	$V_{O} = 0.5 \text{ to } 2.2V,$ $R_{L} = 10 \text{K to V}^{-}$	78	70 <b>67</b>	dB min
		$V_{O} = 0.5 \text{ to } 2.2V,$ $R_{L} = 2K \text{ to } V^{-}$	73	67 <b>63</b>	dB min
Vo	Output Swing High	R <sub>L</sub> = 10K to V <sup>-</sup>	2.59	2.49 <b>2.46</b>	V
		R <sub>L</sub> = 2K to V <sup>-</sup>	2.53	2.45 <b>2.41</b>	min
	Output Swing Low	R <sub>L</sub> = 10K to V <sup>-</sup>	90	100 <b>120</b>	mV max
I <sub>SC</sub>	Output Short Circuit Current	Sourcing to V <sup>-</sup> V <sub>ID</sub> = 200mV <sup>(6)(7)</sup>	48	30 <b>20</b>	mA min
		Sinking to V <sup>+</sup> $V_{ID} = -200 \text{mV}^{(6)(7)}$	65	50 <b>30</b>	mA min
Is	Supply Current	No load, V <sub>CM</sub> = 0.5V	0.95	1.20 <b>1.50</b>	mA max
SR	Slew Rate <sup>(8)</sup>	$A_V = +1, V_I = 2V_{PP}$	9	_	V/µs
f <sub>u</sub>	Unity Gain-Frequency	$V_I = 10$ mV, $R_L = 2$ K $\Omega$ to V <sup>+</sup> /2	10	_	MHz
GBWP	Gain Bandwidth Product	f = 50KHz	21	15.5 <b>14</b>	MHz min
Phi <sub>m</sub>	Phase Margin	V <sub>I</sub> = 10mV	50	_	Deg
e <sub>n</sub>	Input-Referred Voltage Noise	$f = 2KHz$ , $R_S = 50\Omega$	15	_	nV/ √Hz
i <sub>n</sub>	Input-Referred Current Noise	f = 2KHz	1		pA/ √Hz

<sup>(1)</sup> Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that TJ = TA. No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self heating where TJ > TA.

Typical Values represent the most likely parametric norm.

All limits are guaranteed by testing or statistical analysis.

Offset voltage average drift determined by dividing the change in VOS at temperature extremes into the total temperature change.

Positive current corresponds to current flowing into the device. (5)

<sup>(6)</sup> Production Short Circuit test is a momentary test. See Note 7.

Allowable Output Short Circuit duration is infinite for VS ≤ 6V at room temperature and below. For VS > 6V, allowable short circuit duration is 1.5ms.

Slew rate is the slower of the rising and falling slew rates. Connected as a Voltage Follower.



## 2.7V ELECTRICAL CHARACTERISTICS (continued)

Unless otherwise specified, all limits guaranteed for  $T_A = 25^{\circ}C$ ,  $V^+ = 2.7V$ ,  $V^- = 0V$ ,  $V_{CM} = 0.5V$ ,  $V_O = V^+/2$ , and  $R_L > 1M\Omega$  to  $V^-$ . **Boldface** limits apply at the temperature extremes.<sup>(1)</sup>

Symbol	Parameter	Condition	Typ <sup>(2)</sup>	Limit <sup>(3)</sup>	Units
$f_{MAX}$	Full Power Bandwidth	$Z_L = (20pF    10K\Omega) \text{ to } V^+/2$	1	-	MHz

## 5V ELECTRICAL CHARACTERISTICS(1)

Unless otherwise specified, all limited guaranteed for  $T_A = 25^{\circ}C$ ,  $V^+ = 5V$ ,  $V^- = 0V$ ,  $V_{CM} = 1V$ ,  $V_O = V^+/2$ , and  $R_L > 1M\Omega$  to  $V^-$ . **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Condition	Typ <sup>(2)</sup>	Limit <sup>(3)</sup>	Units
V <sub>OS</sub>	Input Offset Voltage	$V_{CM} = 1V \& V_{CM} = 4.5V$	+/-0.7	+/-5 <b>+/- 7</b>	mV max
TC V <sub>OS</sub>	Input Offset Average Drift	V <sub>CM</sub> = 1V & V <sub>CM</sub> = 4.5V <sup>(4)</sup>	+/-2	_	μV/°C
I <sub>B</sub>	Input Bias Current	V <sub>CM</sub> = 1V <sup>(5)</sup>	-1.18	-2.00 - <b>2.70</b>	μA
		$V_{CM} = 4.5V^{(5)}$	+0.49	+1.00 + <b>1.60</b>	max
I <sub>OS</sub>	Input Offset Current	V <sub>CM</sub> = 1V & V <sub>CM</sub> = 4.5V	20	250 <b>400</b>	nA max
CMRR	Common Mode Rejection Ratio	V <sub>CM</sub> stepped from 0V to 3.3V	110	84 <b>72</b>	
		V <sub>CM</sub> stepped from 4V to 5V	100	_	dB min
		V <sub>CM</sub> stepped from 0V to 5V	80	64 <b>61</b>	-
+PSRR	Positive Power Supply Rejection Ratio	$V^{+} = 2.7V$ to 5V, $V_{CM} = 0.5V$	104	78 <b>74</b>	dB min
CMVR	Input Common-Mode Voltage Range	CMRR > 50dB	-0.3	-0.1 <b>0.0</b>	V max
			5.3	5.1 <b>5.0</b>	V min
A <sub>VOL</sub>	Large Signal Voltage Gain	$V_{O} = 0.5 \text{ to } 4.5 \text{V},$ $R_{L} = 10 \text{K to V}^{-}$	84	74 <b>70</b>	dB
		$V_{O} = 0.5 \text{ to } 4.5 \text{V},$ $R_{L} = 2 \text{K to V}^{-}$	80	70 <b>66</b>	min
Vo	Output Swing High	R <sub>L</sub> = 10K to V <sup>-</sup>	4.87	4.75 <b>4.72</b>	V
		$R_L = 2K \text{ to } V^-$	4.81	4.70 <b>4.66</b>	min
	Output Swing Low	R <sub>L</sub> = 10K to V <sup>-</sup>	86	125 <b>135</b>	mV max
I <sub>SC</sub>	Output Short Circuit Current	Sourcing to V <sup>-</sup> V <sub>ID</sub> = 200mV <sup>(6) (7)</sup>	53	35 <b>20</b>	mA
		Sinking to V <sup>+</sup> $V_{ID} = -200 \text{mV}^{(6)(7)}$	75	60 <b>50</b>	min
Is	Supply Current	No load, V <sub>CM</sub> = 1V	0.97	1.25 <b>1.75</b>	mA max

<sup>(1)</sup> Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that TJ = TA. No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self heating where TJ > TA.

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<sup>(2)</sup> Typical Values represent the most likely parametric norm.

<sup>(3)</sup> All limits are guaranteed by testing or statistical analysis.

<sup>(4)</sup> Offset voltage average drift determined by dividing the change in VOS at temperature extremes into the total temperature change.

<sup>(5)</sup> Positive current corresponds to current flowing into the device.

<sup>(6)</sup> Production Short Circuit test is a momentary test. See Note 7.

<sup>(7)</sup> Allowable Output Short Circuit duration is infinite for VS ≤ 6V at room temperature and below. For VS > 6V, allowable short circuit duration is 1.5ms.



# **5V ELECTRICAL CHARACTERISTICS**<sup>(1)</sup> (continued)

Unless otherwise specified, all limited guaranteed for  $T_A = 25^{\circ}C$ ,  $V^+ = 5V$ ,  $V^- = 0V$ ,  $V_{CM} = 1V$ ,  $V_O = V^+/2$ , and  $R_L > 1M\Omega$  to  $V^-$ . **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Condition	Typ <sup>(2)</sup>	Limit <sup>(3)</sup>	Units	
SR	Slew Rate <sup>(8)</sup>	$A_V = +1, V_I = 5V_{PP}$	12	10 <b>7</b>	V/µs min	
f <sub>u</sub>	Unity Gain Frequency	$V_I = 10 \text{mV},$ $R_L = 2 \text{K}\Omega \text{ to V}^+/2$	10.5	_	MHz	
GBWP	Gain-Bandwidth Product	f = 50KHz	21	16 <b>15</b>	MHz min	
Phi <sub>m</sub>	Phase Margin	V <sub>I</sub> = 10mV	53	_	Deg	
e <sub>n</sub>	Input-Referred Voltage Noise	$f = 2KHz, R_S = 50\Omega$	15	_	nV/ √hZ	
i <sub>n</sub>	Input-Referred Current Noise	f = 2KHz	1	_	pA/ √hZ	
f <sub>MAX</sub>	Full Power Bandwidth	$Z_L = (20pF    10k\Omega) \text{ to V}^+/2$	900	_	KHz	
t <sub>S</sub>	Settling Time (±5%)	100mV <sub>PP</sub> Step, 500pF load	400	_	ns	
THD+N	Total Harmonic Distortion + Noise	$R_L = 1K\Omega$ to V <sup>+</sup> /2 f = 10KHz to A <sub>V</sub> = +2, 4V <sub>PP</sub> swing	0.05	-	%	

<sup>(8)</sup> Slew rate is the slower of the rising and falling slew rates. Connected as a Voltage Follower.

## ±15V ELECTRICAL CHARACTERISTICS(1)

Unless otherwise specified, all limited guaranteed for  $T_A = 25^{\circ}C$ ,  $V^+ = 15V$ ,  $V^- = -15V$ ,  $V_{CM} = 0V$ ,  $V_O = 0V$ , and  $R_L > 1M\Omega$  to 0V. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Condition	Typ <sup>(2)</sup>	Limit <sup>(3)</sup>	Units	
V <sub>OS</sub> Input Offset Voltage		V <sub>CM</sub> = -14.5V & V <sub>CM</sub> = 14.5V	+/-0.7	+/-7 + <b>/</b> - 9	mV max	
TC V <sub>OS</sub>	Input Offset Average Drift	$V_{CM} = -14.5V \& V_{CM} = 14.5V^{(4)}$	+/-2	_	μV/°C	
I <sub>B</sub>	Input Bias Current	$V_{CM} = -14.5V^{(5)}$	-1.05	-2.00 <b>-2.80</b>	μA	
		$V_{CM} = 14.5V^{(5)}$	+0.49	+1.00 <b>+1.50</b>	max	
I <sub>OS</sub>	Input Offset Current	$V_{CM} = -14.5V \& V_{CM} = 14.5V$	30	275 <b>550</b>	nA max	
CMRR	Common Mode Rejection Ratio	V <sub>CM</sub> stepped from -15V to 13V	100	84 <b>80</b>		
		V <sub>CM</sub> stepped from 14V to 15V	100	_	dB min	
		V <sub>CM</sub> stepped from -15V to 15V	88	74 <b>72</b>		
+PSRR	Positive Power Supply Rejection Ratio	V <sup>+</sup> = 12V to 15V	100	70 <b>66</b>	dB min	
-PSRR	Negative Power Supply Rejection Ratio	V <sup>-</sup> = −12V to −15V	100	70 <b>66</b>	dB min	
CMVR	Input Common-Mode Voltage Range	CMRR > 50dB	-15.3	-15.1 <b>-15.0</b>	V max	
			15.3	15.1 <b>15.0</b>	V min	
A <sub>VOL</sub>	Large Signal Voltage Gain	$V_O = 0V \text{ to } \pm 13V,$ $R_L = 10K\Omega$	85	78 <b>74</b>	dB	
		$V_O = 0V$ to ±13V, $R_L = 2K\Omega$	79	72 <b>66</b>	min	

<sup>(1)</sup> Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that T<sub>J</sub> = T<sub>A</sub>. No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self heating where T<sub>J</sub> > T<sub>A</sub>.

<sup>(2)</sup> Typical Values represent the most likely parametric norm.

<sup>(3)</sup> All limits are guaranteed by testing or statistical analysis.

<sup>(4)</sup> Offset voltage average drift determined by dividing the change in V<sub>OS</sub> at temperature extremes into the total temperature change.

<sup>(5)</sup> Positive current corresponds to current flowing into the device.



# ±15V ELECTRICAL CHARACTERISTICS(1) (continued)

Unless otherwise specified, all limited guaranteed for  $T_A = 25^{\circ}C$ ,  $V^+ = 15V$ ,  $V^- = -15V$ ,  $V_{CM} = 0V$ ,  $V_O = 0V$ , and  $R_L > 1M\Omega$  to 0V. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Condition	Typ <sup>(2)</sup>	Limit <sup>(3)</sup>	Units
Vo	Output Swing High	$R_L = 10K\Omega$	14.83	14.65 <b>14.61</b>	V
		$R_L = 2K\Omega$	14.73	14.60 <b>14.55</b>	min
	Output Swing Low	$R_L = 10K\Omega$	-14.91	-14.75 - <b>14.65</b>	V
		$R_L = 2K\Omega$	-14.83	-14.65 <b>-14.60</b>	max
I <sub>SC</sub>	Output Short Circuit Current	Sourcing to ground V <sub>ID</sub> = 200mV <sup>(6)(7)</sup>	60	40 <b>25</b>	mA
		Sinking to ground V <sub>ID</sub> = 200mV <sup>(6)</sup> (7)	100	70 <b>60</b>	min
I <sub>S</sub>	Supply Current	No load, V <sub>CM</sub> = 0V	1.30	1.50 <b>1.90</b>	mA max
SR	Slew Rate (8)	$A_V = +1, V_I = 24V_{PP}$	15	10 <b>8</b>	V/µs min
f <sub>u</sub>	Unity Gain Frequency	$V_I = 10 \text{mV}, R_L = 2 \text{K}\Omega$	14	_	MHz
GBWP	Gain-Bandwidth Product	f = 50KHz	24	18 <b>16</b>	MHz min
Phi <sub>m</sub>	Phase Margin	V <sub>I</sub> = 10mV	58	-	Deg
e <sub>n</sub>	Input-Referred Voltage Noise	$f = 2KHz, R_S = 50\Omega$	15	-	nV/ √hZ
i <sub>n</sub>	Input-Referred Current Noise	f = 2KHz	1	_	pA/ √hZ
f <sub>MAX</sub>	Full Power Bandwidth	Z <sub>L</sub> = 20pF    10KΩ	160	-	KHz
ts	Settling Time (±1%, A <sub>V</sub> = +1)	Positive Step, 5V <sub>PP</sub>	320	_	ne
		Negative Step, 5V <sub>PP</sub>	600	_	ns
THD+N	Total Harmonic Distortion +Noise	$R_L = 1K\Omega$ , $f = 10KHz$ , $A_V = +2$ , $28V_{PP}$ swing	0.01	_	%

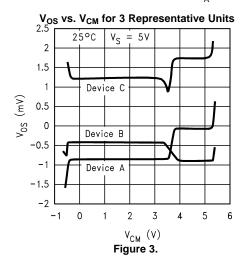
Production Short Circuit test is a momentary test. See Note 7. Allowable Output Short Circuit duration is infinite for  $V_S \le 6V$  at room temperature and below. For  $V_S > 6V$ , allowable short circuit duration is 1.5ms.

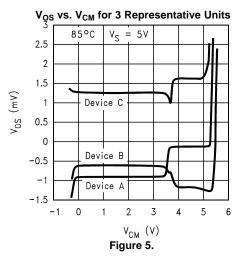
Slew rate is the slower of the rising and falling slew rates. Connected as a Voltage Follower.

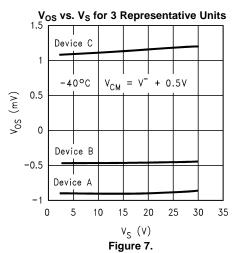


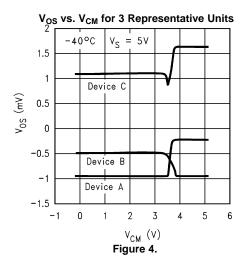
#### TYPICAL PERFORMANCE CHARACTERISTICS

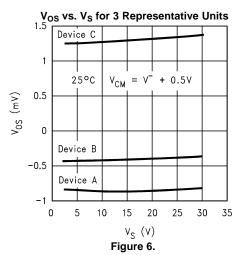
T<sub>A</sub> = 25°C, Unless Otherwise Noted

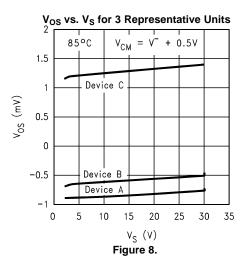






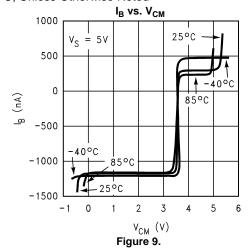


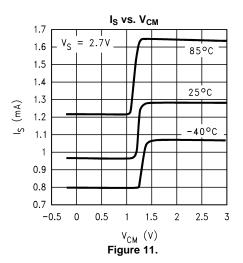


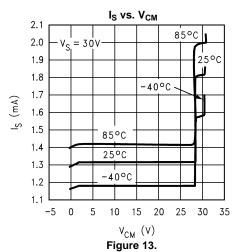


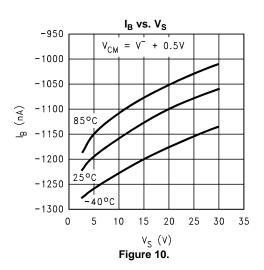


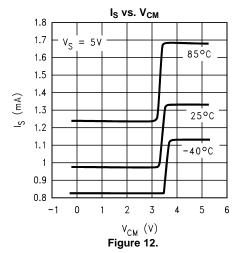
 $T_A = 25$ °C, Unless Otherwise Noted

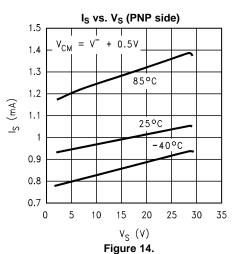














 $T_A = 25$ °C, Unless Otherwise Noted

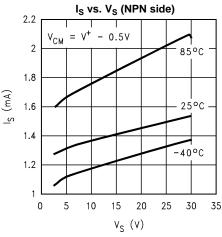
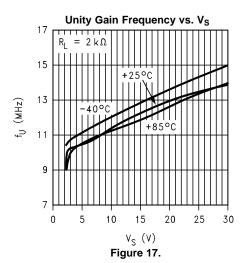
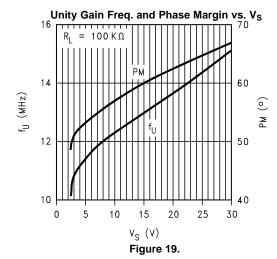
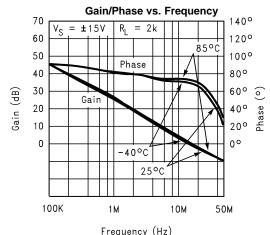


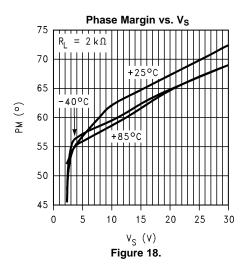
Figure 15.







Frequency (Hz)
Figure 16.



Unity Gain Frequency vs. Load

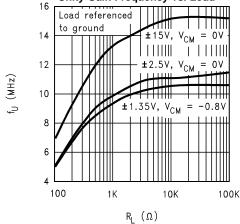
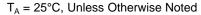


Figure 20.





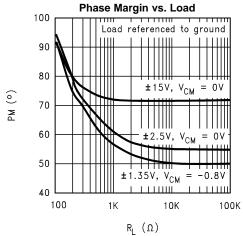
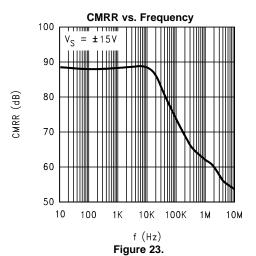


Figure 21.



-PSRR vs. Frequency

100

V<sub>S</sub> = 30V

V<sub>S</sub> = 5V

V<sub>S</sub> = 2.7V

40

10 100 1K 10K 100K 1M

f (Hz)

Figure 25.

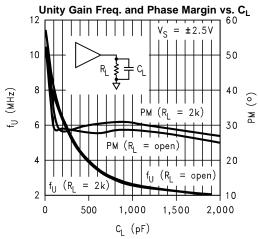
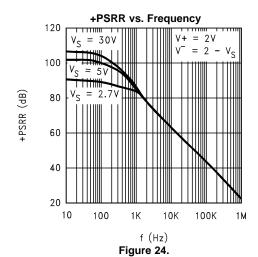


Figure 22.



Output Voltage vs. Output Sourcing Current

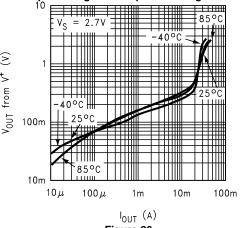
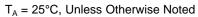


Figure 26.





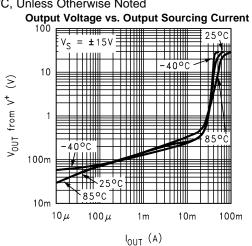
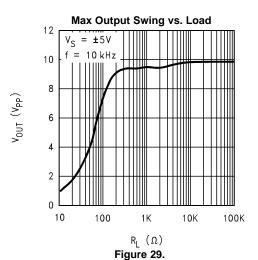


Figure 27.



% Overshoot vs. Cap Load

70

60  $V_S = \pm 5V, A_V = +1$ 100 mV<sub>PP</sub> step

40

30

10p

10p

10p

10op

10op

10op

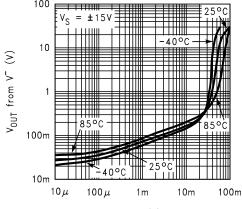
10on

10n

1  $\mu$ 10op  $C_L$  (F)

Figure 31.

Output Voltage vs. Output Sinking Current



ι<sub>ΟUT</sub> (A) **Figure 28.** 

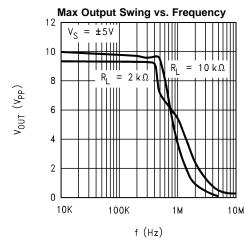


Figure 30.

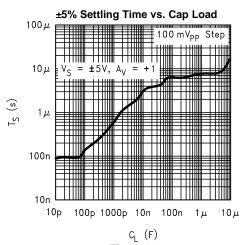
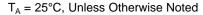


Figure 32.





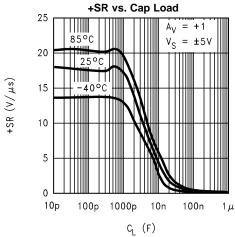


Figure 33.

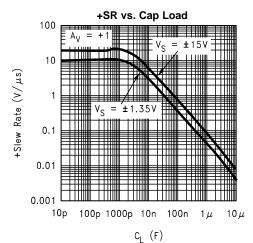
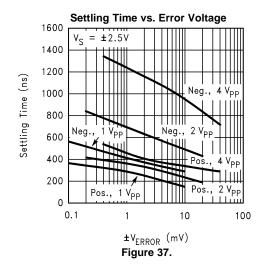


Figure 35.



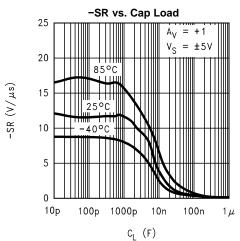
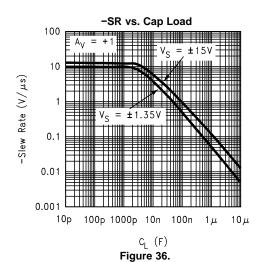


Figure 34.



Settling Time vs. Error Voltage

1200

V<sub>S</sub> = ±15V

Neg., 5 V<sub>PP</sub>

400

Neg., 1 V<sub>PP</sub>

Pos., 5 V<sub>PP</sub>

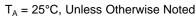
Neg., 2 V<sub>PP</sub>

O..1

1 10 100

±V<sub>ERROR</sub> (mV) Figure 38.





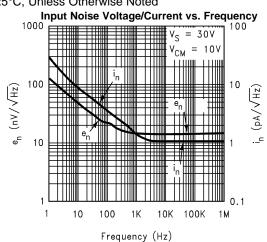


Figure 39.

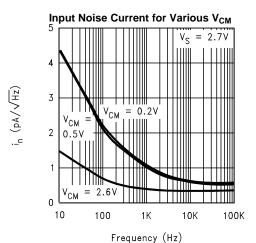
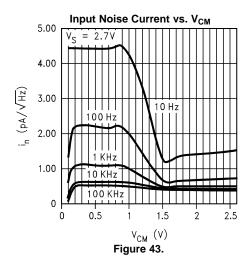


Figure 41.



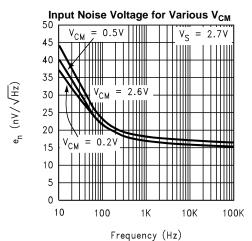


Figure 40.

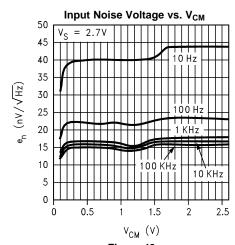


Figure 42.

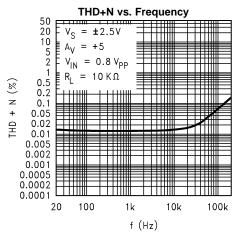
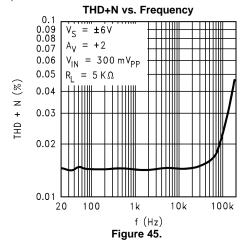
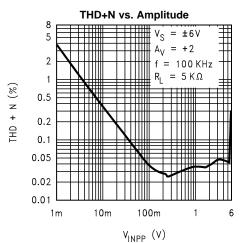


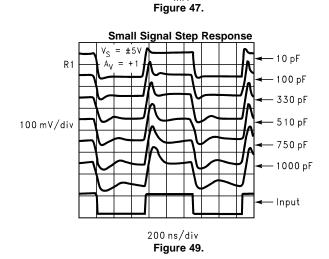
Figure 44.

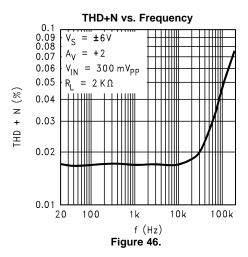


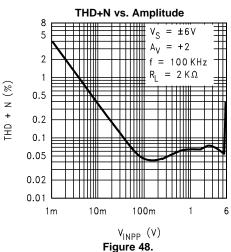
T<sub>A</sub> = 25°C, Unless Otherwise Noted

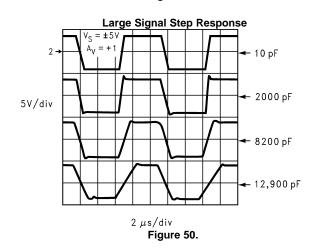














#### APPLICATION HINTS

#### **BLOCK DIAGRAM AND OPERATIONAL DESCRIPTION**

#### A) Input Stage

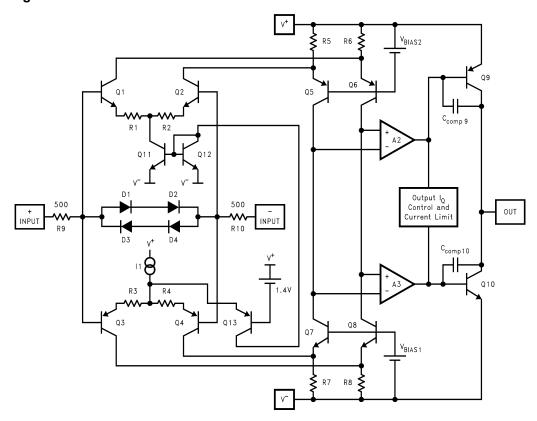


Figure 51. Simplified Schematic Diagram

As can be seen from the simplified schematic in Figure 51, the input stage consists of two distinct differential pairs (Q1-Q2 and Q3-Q4) in order to accommodate the full Rail-to-Rail input common mode voltage range. The voltage drop across R5, R6, R7, and R8 is kept to less than 200mV in order to allow the input to exceed the supply rails. Q13 acts as a switch to steer current away from Q3-Q4 and into Q1-Q2, as the input increases beyond 1.4V of V<sup>+</sup>. This in turn shifts the signal path from the bottom stage differential pair to the top one and causes a subsequent increase in the supply current.

In transitioning from one stage to another, certain input stage parameters ( $V_{OS}$ ,  $I_b$ ,  $I_{OS}$ ,  $e_n$ , and  $i_n$ ) are determined based on which differential pair is "on" at the time. Input Bias current,  $I_B$ , will change in value and polarity as the input crosses the transition region. In addition, parameters such as PSRR and CMRR which involve the input offset voltage will also be effected by changes in  $V_{CM}$  across the differential pair transition region.

The input stage is protected with the combination of R9-R10 and D1, D2, D3, and D4 against differential input over-voltages. This fault condition could otherwise harm the differential pairs or cause offset voltage shift in case of prolonged over voltage. As shown in Figure 52, if this voltage reaches approximately  $\pm 1.4 \text{V}$  at 25°C, the diodes turn on and current flow is limited by the internal series resistors (R9 and R10). The Absolute Maximum Rating of  $\pm 10 \text{V}$  differential on  $\text{V}_{\text{IN}}$  still needs to be observed. With temperature variation, the point were the diodes turn on will change at the rate of 5mV/°C.

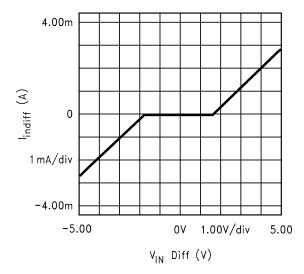


Figure 52. Input Stage Current vs. Differential Input Voltage

#### **B) Output Stage**

The output stage Figure 51 is comprised of complementary NPN and PNP common-emitter stages to permit voltage swing to within a  $V_{CE(SAT)}$  of either supply rail. Q9 supplies the sourcing and Q10 supplies the sinking current load. Output current limiting is achieved by limiting the  $V_{CE}$  of Q9 and Q10; using this approach to current limiting, alleviates the draw back to the conventional scheme which requires one  $V_{BE}$  reduction in output swing.

The frequency compensation circuit includes Miller capacitors from collector to base of each output transistor (see Figure 51, C<sub>comp9</sub> and C<sub>comp10</sub>). At light capacitive loads, the high frequency gain of the output transistors is high, and the Miller effect increases the effective value of the capacitors thereby stabilizing the Op Amp. Large capacitive loads greatly decrease the high frequency gain of the output transistors thus lowering the effective internal Miller capacitance - the internal pole frequency increases at the same time a low frequency pole is created at the Op Amp output due to the large load capacitor. In this fashion, the internal dominant pole compensation, which works by reducing the loop gain to less than 0dB when the phase shift around the feedback loop is more than 180°C, varies with the amount of capacitive load and becomes less dominant when the load capacitor has increased enough. Hence the Op Amp is very stable even at high values of load capacitance resulting in the uncharacteristic feature of stability under all capacitive loads.

## **DRIVING CAPACITIVE LOADS**

The LM8261 is specifically designed to drive unlimited capacitive loads without oscillations (See Settling Time and Percent Overshoot vs. Cap Load plot, Figure 32). In addition, the output current handling capability of the device allows for good slewing characteristics even with large capacitive loads (see Slew Rate vs. Cap Load plots). The combination of these features is ideal for applications such as TFT flat panel buffers, A/D converter input amplifiers, etc.

However, as in most Op Amps, addition of a series isolation resistor between the Op Amp and the capacitive load improves the settling and overshoot performance.

Output current drive is an important parameter when driving capacitive loads. This parameter will determine how fast the output voltage can change. Referring to the Slew Rate vs. Cap Load Plots (Figure 33, Figure 34, Figure 35, and Figure 36), two distinct regions can be identified. Below about 10,000pF, the output Slew Rate is solely determined by the Op Amp's compensation capacitor value and available current into that capacitor. Beyond 10nF, the Slew Rate is determined by the Op Amp's available output current. Note that because of the lower output sourcing current compared to the sinking one, the Slew Rate limit under heavy capacitive loading is determined by the positive transitions. An estimate of positive and negative slew rates for loads larger than 100nF can be made by dividing the short circuit current value by the capacitor.



For the LM8261, the available output current increases with the input overdrive. Referring to Figure 53 and Figure 54, Output Short Circuit Current vs. Input Overdrive, it can be seen that both sourcing and sinking short circuit current increase as input overdrive increases. In a closed loop amplifier configuration, during transient conditions while the fed back output has not quite caught up with the input, there will be an overdrive imposed on the input allowing more output current than would normally be available under steady state condition. Because of this feature, the Op Amp's output stage quiescent current can be kept to a minimum, thereby reducing power consumption, while enabling the device to deliver large output current when the need arises (such as during transients).

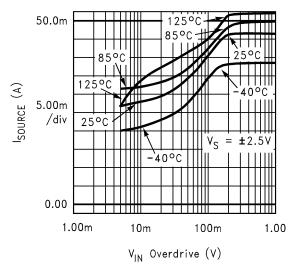


Figure 53. Output Short Circuit Sourcing Current vs. Input Overdrive

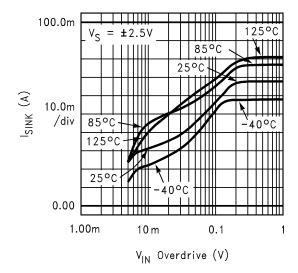


Figure 54. Output Short Circuit Sinking Current vs. Input Overdrive

Figure 55 shows the output voltage, output current, and the resulting input overdrive with the device set for  $A_V = +1$  and the input tied to a  $1V_{PP}$  step function driving a 47nF capacitor. As can be seen, during the output transition, the input overdrive reaches 1V peak and is more than enough to cause the output current to increase to its maximum value (see Figure 53 and Figure 54 plots). Note that because of the larger output sinking current compared to the sourcing one, the output negative transition is faster than the positive one.



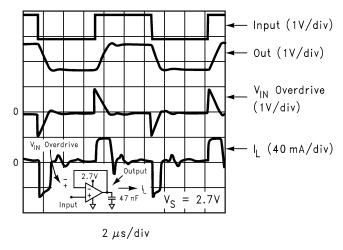


Figure 55. Buffer Amplifier scope photo

#### **ESTIMATING THE OUTPUT VOLTAGE SWING**

It is important to keep in mind that the steady state output current will be less than the current available when there is an input overdrive present. For steady state conditions, the Output Voltage vs. Output Current plot ( TYPICAL PERFORMANCE CHARACTERISTICS section) can be used to predict the output swing. Figure 56 and Figure 57 show this performance along with several load lines corresponding to loads tied between the output and ground. In each cases, the intersection of the device plot at the appropriate temperature with the load line would be the typical output swing possible for that load. For example, a  $1K\Omega$  load can accommodate an output swing to within 250mV of  $V^-$  and to 330mV of  $V^+$  ( $V_S = \pm 15V$ ) corresponding to a typical 29.3 $V_{PP}$  unclipped swing.

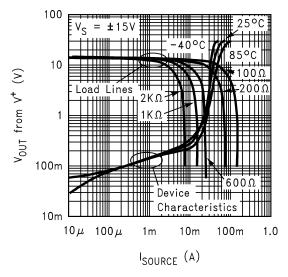


Figure 56. Output Sourcing Characteristics with Load Lines



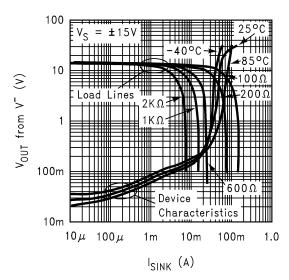


Figure 57. Output Sinking Characteristics with Load Lines

#### **TFT APPLICATIONS**

Figure 58 below, shows a typical application where the LM8261 is used as a buffer amplifier for the V<sub>COM</sub> signal employed in a TFT LCD flat panel:

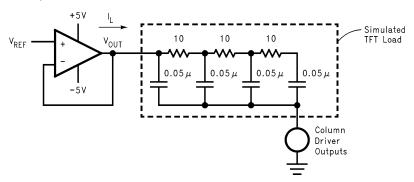


Figure 58. V<sub>COM</sub> Driver Application Schematic

Figure 59 shows the time domain response of the amplifier when used as a V<sub>COM</sub> buffer/driver with V<sub>REF</sub> at ground. In this application, the Op Amp loop will try and maintain its output voltage based on the voltage on its non-inverting input (V<sub>REF</sub>) despite the current injected into the TFT simulated load. As long as this load current is within the range tolerable by the LM8261 (45mA sourcing and 65mA sinking for ±5V supplies), the output will settle to its final value within less than 2µs.

Product Folder Links: LM8261

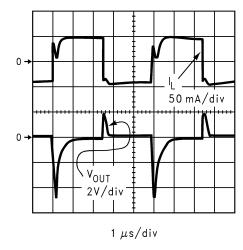


Figure 59. V<sub>COM</sub> driver performance scope photo

#### **OUTPUT SHORT CIRCUIT CURRENT AND DISSIPATION ISSUES**

The LM8261 output stage is designed for maximum output current capability. Even though momentary output shorts to ground and either supply can be tolerated at all operating voltages, longer lasting short conditions can cause the junction temperature to rise beyond the absolute maximum rating of the device, especially at higher supply voltage conditions. Below supply voltage of 6V, output short circuit condition can be tolerated indefinitely.

With the Op Amp tied to a load, the device power dissipation consists of the quiescent power due to the supply current flow into the device, in addition to power dissipation due to the load current. The load portion of the power itself could include an average value (due to a DC load current) and an AC component. DC load current would flow if there is an output voltage offset, or the output AC average current is non-zero, or if the Op Amp operates in a single supply application where the output is maintained somewhere in the range of linear operation. Therefore:

 $P_{TOTAL} = P_Q + P_{DC} + P_{AC}$ 

 $P_Q = I_S \cdot V_S$  Op Amp Quiescent Power Dissipation

 $P_{DC} = I_O \cdot (V_R - V_O)$  DC Load Power  $P_{AC} = \text{See Table 1 below}$  AC Load Power

where:

Is: Supply Current

V<sub>S</sub>: Total Supply Voltage (V<sup>+</sup> - V<sup>-</sup>)

I<sub>O</sub>: Average load current

V<sub>O</sub>: Average Output Voltage

V<sub>R</sub>: V<sup>+</sup> for sourcing and V<sup>-</sup> for sinking current

Table 1 below shows the maximum AC component of the load power dissipated by the Op Amp for standard Sinusoidal, Triangular, and Square Waveforms:

Table 1. Normalized AC Power Dissipated in the Output Stage for Standard Waveforms

	$P_{AC}$ (W. $\Omega/V^2$ )	
Sinusoidal	Triangular	Square
50.7 x 10 <sup>-3</sup>	46.9 x 10 <sup>-3</sup>	62.5 x 10 <sup>-3</sup>

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The table entries are normalized to  $V_S^2/R_L$ . To figure out the AC load current component of power dissipation, simply multiply the table entry corresponding to the output waveform by the factor  $V_S^2/R_L$ . For example, with ±15V supplies, a  $600\Omega$  load, and triangular waveform power dissipation in the output stage is calculated as:

 $P_{AC} = (46.9 \times 10^{-3}) \cdot [30^2/600] = 70.4 \text{mW}$ 

### **Other Application Hints**

The use of supply decoupling is mandatory in most applications. As with most relatively high speed/high output current Op Amps, best results are achieved when each supply line is decoupled with two capacitors; a small value ceramic capacitor ( $\sim 0.01 \mu F$ ) placed very close to the supply lead in addition to a large value Tantalum or Aluminum (>  $4.7 \mu F$ ). The large capacitor can be shared by more than one device if necessary. The small ceramic capacitor maintains low supply impedance at high frequencies while the large capacitor will act as the charge "bucket" for fast load current spikes at the Op Amp output. The combination of these capacitors will provide supply decoupling and will help keep the Op Amp oscillation free under any load.

#### LM8261 ADVANTAGES

Compared to other Rail-to-Rail Input/Output devices, the LM8261 offers several advantages such as:

- Improved cross over distortion.
- Nearly constant supply current throughout the output voltage swing range and close to either rail.
- Consistent stability performance for all input/output voltage and current conditions.
- Nearly constant Unity gain frequency (f<sub>u</sub>) and Phase Margin (Phi<sub>m</sub>) for all operating supplies and load conditions.
- No output phase reversal under input overload condition.

### SNOS469I - APRIL 2000 - REVISED MARCH 2013



## **REVISION HISTORY**

Changes from Revision H (March 2013) to Revision I					
•	Changed layout of National Data Sheet to TI format	21			





13-Mar-2013

#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	_		Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing			(2)		(3)		(4)	
LM8261M5	ACTIVE	SOT-23	DBV	5	1000	TBD	Call TI	Call TI	-40 to 85	A45A	Samples
LM8261M5/NOPB	ACTIVE	SOT-23	DBV	5	1000	Green (RoHS & no Sb/Br)	SN	Level-1-260C-UNLIM	-40 to 85	A45A	Samples
LM8261M5X	ACTIVE	SOT-23	DBV	5	3000	TBD	Call TI	Call TI	-40 to 85	A45A	Samples
LM8261M5X/NOPB	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	SN	Level-1-260C-UNLIM	-40 to 85	A45A	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

<sup>&</sup>lt;sup>(4)</sup> Only one of markings shown within the brackets will appear on the physical device.

## PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM8261M5	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM8261M5/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM8261M5X	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM8261M5X/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

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\*All dimensions are nominal

7 til dilliononono di o momina							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM8261M5	SOT-23	DBV	5	1000	210.0	185.0	35.0
LM8261M5/NOPB	SOT-23	DBV	5	1000	210.0	185.0	35.0
LM8261M5X	SOT-23	DBV	5	3000	210.0	185.0	35.0
LM8261M5X/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0

# DBV (R-PDSO-G5)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-178 Variation AA.



# DBV (R-PDSO-G5)

# PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



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